

High Performance Schottky Rectifier, 200 A


TO-244

FEATURES

- 175 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

PRIMARY CHARACTERISTICS	
I _{F(AV)}	200 A
V _R	50 V
Package	TO-244
Circuit configuration	Two diodes common cathode

DESCRIPTION / APPLICATIONS

The VS-201CNQ050PbF center tap Schottky rectifier module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform	200	A
V _{RRM}		50	V
I _{FSM}	t _p = 5 μs sine	16 000	A
V _F	100 A _{pk} , T _J = 125 °C (per leg)	0.58	V
T _J	Range	-55 to +175	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	201CNQ050PbF	UNITS
Maximum DC reverse voltage	V _R	50	V
Maximum working peak reverse voltage	V _{RWM}		

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 146 °C, rectangular waveform	200	A
			100	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	16 000
		10 ms sine or 6 ms rect. pulse		2000
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 17 A, L = 1 mH	145	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A = 1.5 x V _R typical	20	A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1	$V_{FM}^{(1)}$	100 A	$T_J = 25\text{ }^\circ\text{C}$	0.67	V
		200 A		0.81	
		100 A	$T_J = 125\text{ }^\circ\text{C}$	0.58	
		200 A		0.71	
Maximum reverse leakage current per leg See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	10	mA
		$T_J = 125\text{ }^\circ\text{C}$		90	
Maximum junction capacitance per leg	C_T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$		5200	pF
Typical series inductance per leg	L_S	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s

Note(1) Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}	- 55	-	175	$^\circ\text{C}$
Thermal resistance, junction to case per leg per module	R_{thJC}	-	-	0.38	$^\circ\text{C/W}$
		-	-	0.19	
Thermal resistance, case to heatsink	R_{thCS}	-	0.10	-	
Weight		-	68	-	g
			2.4		oz.
Mounting torque		35.4 (4)	-	53.1 (6)	lbf · in (N · m)
Mounting torque center hole		30 (3.4)	-	40 (4.6)	
Terminal torque		30 (3.4)	-	44.2 (5)	
Vertical pull		-	-	80	lbf · in
2" lever pull		-	-	35	



Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

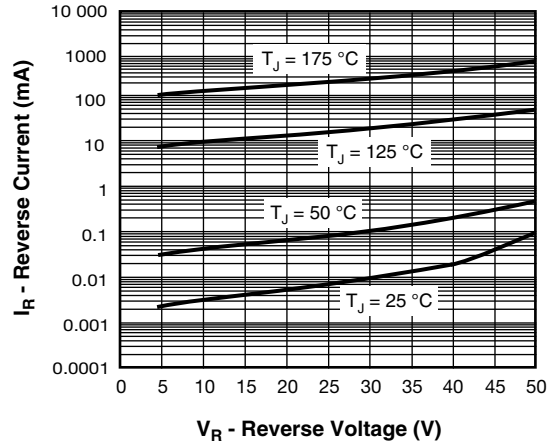


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

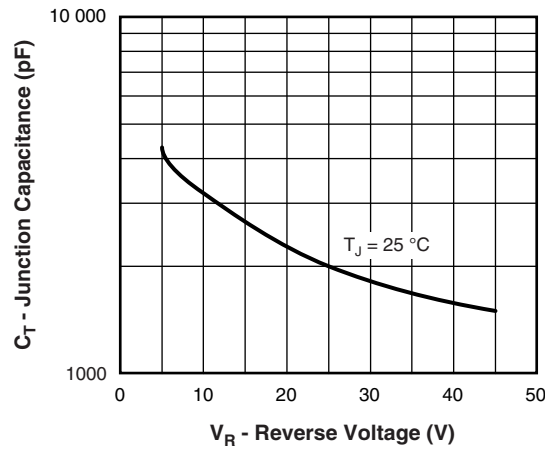


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

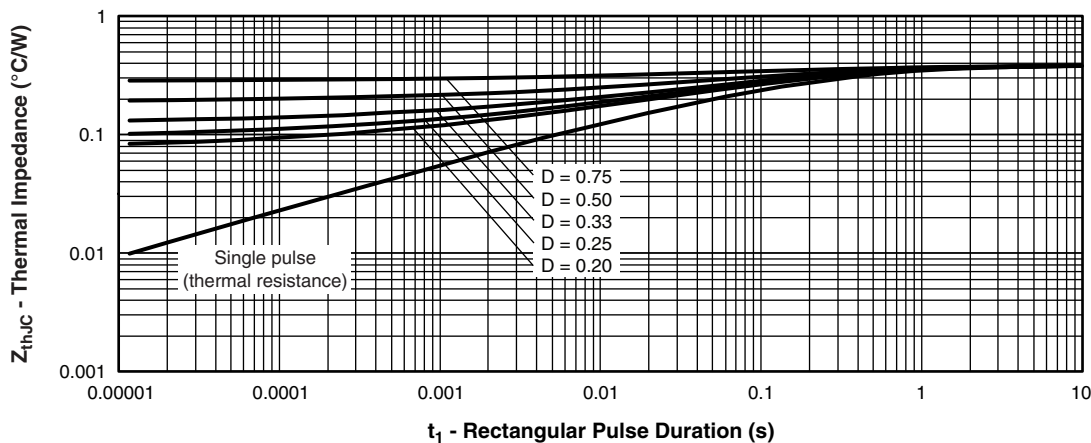


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

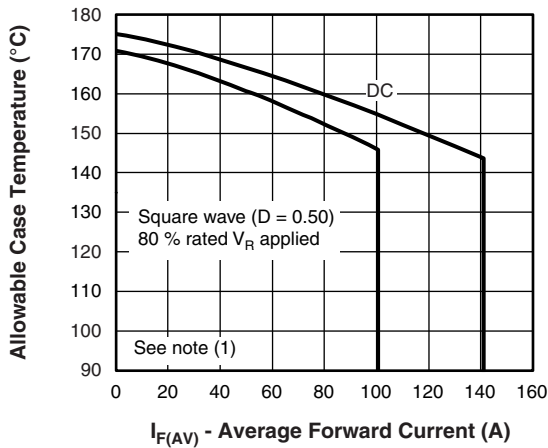


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

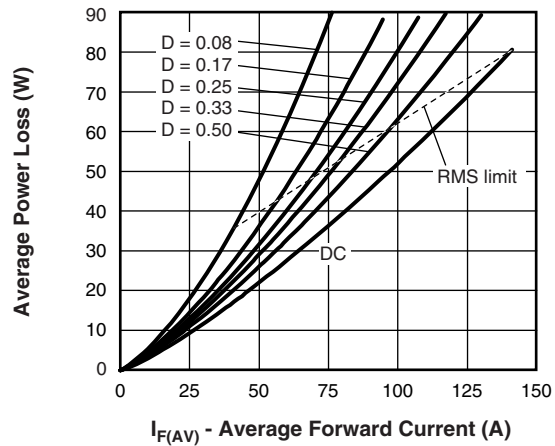


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

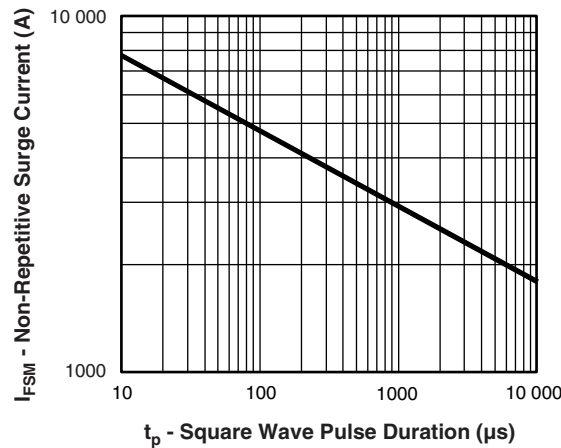


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)



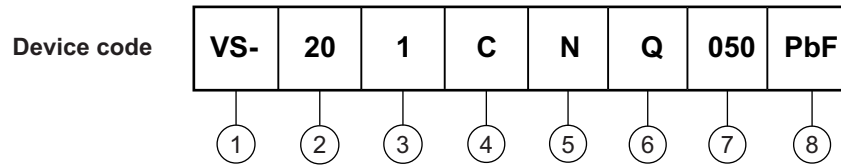
Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 P_d = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 $P_{d_{REV}}$ = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R



ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Average current rating (x 10)
- 3** - Product silicon identification
- 4** - C = circuit configuration
- 5** - N = not isolated
- 6** - Q = Schottky rectifier diode
- 7** - Voltage rating (050 = 50 V)
- 8** - Lead (Pb)-free

LINKS TO RELATED DOCUMENTS

Dimensions	www.vishay.com/doc?95021
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